

WHAT IS CLAIMED IS:

1. A method of forming a narrow writer pole of a write element, the method comprising steps of:
 - (a) forming a non-magnetic layer;
 - (b) forming a writer pole portion on the non-magnetic layer having first and second side walls which define a width of a magnetically active region, the width of the magnetically active region defining a track width of the write element; and
 - (c) transforming the first side wall into a magnetically dead side wall thereby reducing the width of the magnetically active region and the track width of the write element by a thickness of the magnetically dead first side wall.
2. The method of claim 1, including a step (d) of transforming the second side wall into a magnetically dead side wall thereby further reducing the width of the magnetically active region and the track width of the write element by a thickness of the magnetically dead second side wall.
3. The method of claim 1, wherein the forming step (b) is performed in accordance with at least one process selected from a group consisting of sputter deposition, photolithography, etching, milling, and electroplating.

4. The method of claim 1, wherein the transforming step (c) is performed in accordance with at least one process selected from a group consisting of irradiation and ion implantation.
5. The method of claim 4, wherein an element used in ion implantation is selected from a group consisting of nitrogen, argon, boron, phosphorous, and gallium.
6. The method of claim 2, wherein the transforming steps (c) and (d) are performed in accordance with at least one process selected from a group consisting of irradiation and ion implantation.
7. The method of claim 6, wherein an element used in ion implantation is selected from a group consisting of nitrogen, argon, boron, phosphorous, and gallium.
8. The method of claim 1, wherein the forming step (b) includes:
 - (b)(1) forming photoresist dams on the non-magnetic layer;
 - (b)(2) forming the writer pole portion between the photoresist dams; and
 - (b)(3) removing the photoresist dams.
9. The method of claim 1, wherein the writer pole is either a top pole or a bottom pole of the write element.
10. A write element comprising:

a return pole;
a writer gap layer adjacent the return pole; and
a writer pole separated from the return pole by the writer gap layer
and having a width and a magnetically active region
adjoining a first magnetically dead side wall;
wherein the magnetically active region defines a width of the write
element, which is less than a width of the writer pole.

11. The write element of claim 10, including a second magnetically dead side wall opposite the first magnetically dead side wall and having a thickness, whereby the width of the write element is the width of the writer pole less the thicknesses of the first and second magnetically dead side walls.
12. The write element of claim 10, wherein the first magnetically dead side wall is formed of a magnetic material implanted with an element selected from a group consisting of nitrogen, argon, boron, phosphorous, and gallium.
13. The write element of claim 11, wherein the first and second magnetically dead side walls are formed of a magnetic material implanted with an element selected from a group consisting of nitrogen, argon, boron, phosphorous, and gallium.
14. The write element of claim 10, wherein the writer pole is either a bottom pole or a top pole.

15. A disc drive storage system including the write element of claim 10.
16. A write element comprising:
a writer gap layer formed adjacent a return pole;
a writer pole formed adjacent the writer gap layer opposite the
return pole and having an active region whose width defines
a width of the write element; and
an active region reducing means for reducing the width of the
active region without reducing a width of the writer pole.
17. The write element of claim 16, wherein the active region reducing
means includes at least one magnetically dead side wall adjoining the
active region.
18. The write element of claim 17, wherein the magnetically dead side
wall is formed of a magnetic material implanted with an element selected
from a group consisting of nitrogen, argon, boron, phosphorous, and
gallium.
19. A disc drive storage system including the write element of claim 16.